

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	32	257/656.cccls. and schottky	USPAT; EPO; JPO; Derwen t; IBM TDB	2001/02/27 10:04
2	BRS	L2	379	(pin adj diode) and schottky	USPAT; EPO; JPO; Derwen t; IBM TDB	2001/02/27 10:05
3	BRS	L3	242	2 and semiconductor	USPAT; EPO; JPO; Derwen t; IBM TDB	2001/02/27 10:06
4	BRS	L4	49	3 and (impurity or dopant) and concentration	USPAT; EPO; JPO; Derwen t; IBM TDB	2001/02/27 10:06

	Comments	Error Definition	Errors
1			0
2			0
3			0
4			0